# N on-equilibrium spin polarization e ect in spin-orbit coupling system and contacting leads

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W e study theoretically the current-induced spin polarization e ect in a two-term inal mesoscopic structure which is composed of a sem iconductor two-dimensional electron gas (2DEG) bar with R ashba spin-orbit (SO) interaction and two attached ideal leads. The nonequilibrium spin density is calculated by solving the scattering wave functions explicitly within the ballistic transport regime. W e found that for a R ashba SO system the electrical current can induce spin polarization in the SO system as well as in the ideal leads. The induced polarization in the 2DEG shows some equalitative features of the intrinsic spin H all e ect. On the other hand, the nonequilibrium spin density in the ideal leads, after being averaged in the transversal direction, is independent of the distance measured from the lead/SO system interface, except in the vicinity of the interface. Such a lead polarization e ect can even be enhanced by the presence of weak impurity scattering in the SO system and m ay be detectable in real experiments.

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#### I. IN TRODUCTION

Recently there has been hot research interest in spinpolarized transport phenom ena in sem iconductor system s with spin-orbit (SO) coupling because of their potential applications in the eld of sem iconductor spintronics<sup>1,2,3</sup>. One of the principal challenges in sem iconductor spintronics is the e cient injection and effective manipulation of non-equilibrium spin densities and/or spin currents in nonm agnetic sem iconductors by electric m eans, and within this context, the recently predicted phenomenon of intrinsic spin Halle ect would be much attractive. This phenom enon was conceived to survive in some sem iconductor system s with intrinsic spin-orbit interactions and it consists of a spin current contribution in the direction perpendicular to a driving charge current circulating through a sam ple. This phenom enon was rstly proposed to survive in p-doped bulk sem iconductors with spin-orbit split band structures by M urakam i et al.4 and in two-dimensional electronic system swith Rashba spin-orbit coupling by Sinova et al. In the last two years lots of theoretical work have been devoted to the study of this phenom enon and intensive debates arose on som e fundam ental issues concerning this e ect.<sup>6,7,8,9,10,11,12,13,14,15,16,17,18,19,20</sup> Now it was wellestablished that this e ect should be robust against im purity scattering in a mesoscopic sem iconductor system with intrinsic spin-orbit coupling, but it cannot survive in a di usive two-dimensional electron gas with k-linear intrinsic spin-orbit coupling due to vertex correction from in purity scattering.9,10,11,20. It also should be noted that, prior to the prediction of this e ect, a similar phenom enon called extrinsic spin Hall e ect had also been predicted by Dyakanov-Perel<sup>21</sup> and Hirsch<sup>22,23</sup>. Unlike the intrinsic spin Halle ect, the extrinsic spin Hall effect arises from spin-orbit dependent in purity scattering and hence it is a much weak e ect compared with the intrinsic spin Halle ect, and especially, it will disappear

com pletely in the absence of spin-orbit dependent in purity scattering.

A physical quantity which is intuitively a direct consequence of a spin Halle ect in a sem iconductor strip is the nonequilibrium spin accumulation near the transversal boundaries of the strip when a longitudinal charge current circulates through it. The recent experim ental observations in n-doped bulk GaAs<sup>24</sup> and in p-doped two-dimensional G aA  $s^{25}$  have revealed the possibility of generating non-equilibrium edge spin accumulation in a sem iconductor strip by an extrinsic<sup>24</sup> or intrinsic<sup>25</sup> spin Hall e ect, though from the theoretical points of view som e signi cant controversies may still exist for the detailed theoretical interpretations of som e experimental data.<sup>15,19,27,28,29</sup>. It also should be noticed that, in addition to the spin Hall e ect, there may be some other physical reasons that m ay lead to the generation of electric-current-induced spin polarization in a spinorbit coupled system . For example, the experim ental results reported in R ef<sup>26</sup> had dem onstrated another kind of electric-current-induced spin polarization e ect in a spinorbit coupled system, which can be interpreted as the inverse of the photogalvanic e  $\operatorname{ect}^{26}$ . In the present paper we are interested in the question that, besides the transverse boundary spin accum ulations, what kinds of other physical consequences can be predicted for a sem iconductor strip with intrinsic SO coupling. To be speci c, we will consider a strip of a mesoscopic two-dimensional electron gas with Rashba spin-orbit coupling connected to two ideal leads. For such a system, we show that when a longitudinal charge current circulates through the strip, besides the transverse boundary spin accumulations in the strip, non-equilibrium spin polarizations can also be induced in the leads, and the non-equilibrium spin polarizations in the leads will also depend sensitively on the spin-orbit coupling param eters in the strip. Furtherm ore we will show that in the absence of spin-orbit coupling in the leads, the non-equilibrium spin polarizations in the leads will be independent of the distance away from the

border between the lead and the strip, except in the vicinity of the border where local states play an important role. The signs and the amplitudes of the non-equilibrium spin polarization in the leads is adjustable by switching the charge current direction and by tuning the Rashba SO coupling strength in the strip. Furtherm ore, in the presence of weak disorder inside the SO strip, the spin polarization e ect in the leads can be even enhanced while spin polarization in the strip is decreased, so such an e ect m ight be more easily detectable than the spin polarization inside the strip. The non-equilibrium lead polarization e ect provides a new possibility of all-electric control on spin degree of freedom in sem iconductor and thus have practical application potential.

The paper will be organized as following: In section II the model H am iltonian and the theoretical form alism used in the calculations will be introduced. In section III some symmetry properties and numerical results about the non-equilibrium spin polarizations both in the strip and in the leads will be presented and discussed. At last, we sum marize main points of the paper in section IV.

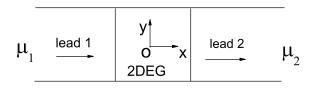


FIG.1: schem atic geom etry of multi-term inal setup.

The system that we will consider in the present paper is depicted in Fig.1, which consists of a strip of a mesoscopic R ashba two-dim ensional electron gas connected to two half-in nite ideal leads. Each lead is connected to an electron reservoir at in nity which has a xed chem ical potential. In the tight binding representation, the H am iltonian for the total system reads:

Here t =  $\frac{h^2}{2m a^2}$  is the hopping parameter between two nearest-neighbor sites where m is elective m ass of electrons and a the lattice constant in the 2DEG bar.  $y_{R_i} = (C_{R_i;"}; C_{R_i;\#})$  is the spinor vector for the site  $R_i$   $(R_i = (x;y))$  in the Rashba SO system. x; y are the standard paulimetrices.  $C_{p_j}$  is the annihilation operator for the site  $p_j$  with spin in lead p.  $p_n$  and  $R_n$ stand for nearest-neighbor pair on the two sides across the interface of the SO system and the lead  $p. w_{R_i}$  is the on-site energy in the SO system, which can readily incorporate random in purity potential. In a pure system we always set  $w_{R_i}$  to zero.  $t_R$  is Rashba coupling coe cient.

Our calculations will follow the same spirit of the usual Landauer-Buttiker's approach. But unlike the frequently used Green's function formalism<sup>12,30</sup>, in the formalism used in the present paper we will solve the scattering wave functions in the whole system explicitly. To this end, we ratly consider the scattering wave of an electron incident from a lead. The real space wave function of an incident electron with spin will be denoted as  $e^{ik_{m}^{p}x_{p}}$ ,  $m_{m}^{p}$ ,  $(y_{p})$ , where  $m_{m}^{p}$ ,  $(y_{p})$  denotes the m 'th transverse mode with spin index in the lead p and  $k_m^p$  the longitudinal wave vector. W e adopt the local coordinate scheme for all leads. In the local coordinate scheme, the longitudinal coordinate x<sub>q</sub> in lead q will take the integer num bers 1;2;...,1 away from the 2DEG interface and the transverse coordinate y<sub>q</sub> take the value of  $N_q=2$ ; ...; $N_q=2$ . The longitudinal wave vector  $k_m^p$  satises the relation  $2t\cos(k_m^p) + \mathbf{u}_m^p = E$ , where  $\mathbf{u}_m^m$  is the eigen-energy of the m 'th transverse m ode in lead p and E the energy of the incident electron. Including both the incident and re ected waves, the total wave function in the lead q has the the following general form :

where  $\begin{array}{c} pm \\ qn \end{array}$  , stands for the scattering am plitude from the (m) mode in lead p to the (n $^{0}$ ) mode in lead q. The scattering amplitudes  $\frac{pm}{qn}$  , will be determined by solving the Schrodinger equation for the entire system, which has now a lattice form and hence there is a separate equation for each lattice site and spin index. Since Eq.(2) is a linear combination of all out-going modes with the same energy E, the Schrodinger equation is satis ed autom atically in lead q, except for the lattice sites in the rst row (i.e.,  $x_q = 1$ ) of the lead that are connected directly to the 2DEG bar. The wave function in the rst row of a lead, which are determined by the scattering amplitudes  $\frac{pm}{qn}$  , must be solved with the wave function in the 2DEG bar simultaneously due to the coupling between the lead and the 2DEG bar. To sim plify the notations, we de ne the wave function in the 2DEG bar as a column vector whose dimension is 2N (N is the total num ber of lattice sites in the 2DEG bar). The scattering am plitudes  $m_{\text{qn}}^{\text{pm}}$  , will be arranged as a colum n vector whose dimension is 2M (M is the total number of lattice sites in the rst row of the leads). From the lattice form of the Schrodinger equations for the 2DEG bar and the

rst row of a lead, one can obtain the following equations re ecting the mutual in uence between the two parts:

$$A = b + B ;$$
  
 $C = d + D ;$  (3)

where A and C are two square matrices with a dimension of 2N 2N and 2M 2M, respectively; B and D are two rectangularm atrices describing the coupling between the leads and the 2D EG bar, whose matrix elements will depend on the actual form of the geometry of the system. The vectors b and d describe the contributions from the incident waves. Some details of deduction as well as the elements of these matrices and vectors have been given elsew here<sup>31</sup>.

After obtaining all scattering amplitudes  ${}_{qn}^{pm}$ , we can calculate the charge current in each lead through the Landauer-Buttiker formula,  $I_p = (e^2=h)_{q}^{-1}; {}_{2}(T_{p}^{q} {}_{2}V_{q} {} {}_{1}T_{q}^{p} {}_{1}^{2}V_{p})$ , where  $V_q = {}_{q} = (e)$  is the voltage applied in the lead q and  ${}_{q}$  is the chem ical potential in the lead q,  $T_{q}^{p}$ , are the transmission probabilities de ned by  $T_{q}^{p}$ ,  $= {}_{m,n} j {}_{qn}^{pm} {}_{0} j^{2}V_{qn} = v_{pm}$  and  $v_{pm} = 2t \sin(k_{m}^{p})$  is the velocity for the m'th mode in the lead p.

W ith the wave function  $\frac{pm}{o}$  (R<sub>i</sub>) in the 2DEG strip at hand, the non-equilibrium spin density in the 2DEG strip can also be calculated readily by taking proper ensemble average following Landauer's spirit<sup>33</sup>. We assume that the reservoirs connecting the leads at innity will feed one-way moving particles to the leads according to their own chemical potential. Following the Landauer's spirit<sup>33</sup>, let's norm alize the scattering wave function pm so that there is one particle for each incident wave, i.e., we normalize  $e^{ik \frac{p}{m} x_p} m_m^p (y_p)$ to  $e^{ik \frac{p}{m} x_p} \frac{p}{m} (y_p) = \overline{L}$ , where L ! 1 is the length of lead p. M eanwhile, the density of states in lead p is  $\frac{L}{2} \frac{dk}{dE} = \frac{L}{2 hv_{pm}}$ , where  $v_{pm} = 2t \sin(k_m^p)$  is the velocity of the m'th transverse mode in lead p. Adding the contributions of all incident channels of lead p with corresponding density of states (DOS), we can obtain the total non-equilibrium spin density. In the linear transport regime, the spin density can be calculated with the incident energy at the Ferm i surface as:

$$hS (R_{i})i = \frac{1}{2} \sum_{pm}^{X} \sum_{pm}^{pm} hv_{pm} \sum_{0,00}^{pm} (R_{i}) \sim 0, 00 \sum_{0,00}^{pm} (R_{i})$$
(4)

where hS  $(R_i)i$  denotes the spin density at a lattice site  $R_i$  in the 2DEG strip and  $_p$  is the chem ical potential of lead p.

### III. RESULTS AND DISCUSSIONS

W hen the system is in the equilibrium state, there will be no net spin density since the Ham iltonian has timereversal (T) symmetry. However, as a charge current ows from lead 1 to lead 2, non-equilibrium spin density may emerge in the whole system, both inside the Rashba bar and in the leads. In this section we will investigate the non-equilibrium spin density under the condition of a xed longitudinal charge current density. In our calculations we will take the typical values of the electron e ective mass  $m = 0.04 m_e$  and the lattice constant  $a = 3nm^{34}$ . The chem ical potential di erence between the two leads will be set by xing the longitudinal charge current density to the experimental value (

100 A=1.5 m ) as reported in R ef<sup>5</sup> and the Ferm ienergy of the 2D EG bar will be set to  $E_f = -3.8t$  throughout the calculations. W e will lim it our discussions to the linear transport regime at zero temperature.

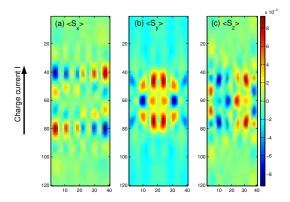


FIG.2: (Coloronline)Typicalpattern of current-induced nonequilibrium spin density (in units of  $\frac{h}{4}$ ) in a two term inal structure. The lattice size for the central SO bar is 40 40. The Rashba coupling strength is taken as  $t_R = 0.1t$ .

To show clearly the characteristics of the currentinduced spin polarization in a two-term inal structure, below we will study the spin density in the Rashba bar and in the leads separately. Firstly we study the spin density in the Rashba bar. The typical spin density pattern obtained in a two term inal structure is shown in Fig.2. From the gures one can see that the spatial distribution of the spin density inside the Rashba bar exhibits som e apparent sym m etry properties, which are sum m arized in Eq.(5) given below. Theoretically speaking, these symmetry properties are the results of some symmetry operations implicit in the two-term inal problem. Let us .explain this point in some more detail. From the symm etry property of the H am iltonian (1) and the rectangular geometry of the system shown in Fig.1, one can see that in our problem we have two symmetry operations  $i_y P_x$  and  $i_x P_y$ , where  $P_x$  and  $P_y$  denote the spacial reection manipulation y! y and x! x respectively and i  $_{\rm x}$  and i  $_{\rm y}$  the spin rotation m anipulation with the angle around the S<sub>x</sub> and S<sub>y</sub> axes in spin space respectively. By considering these symmetry operations, from Eq.(4) one can obtain immediately the following symmetry relations $^{31}$ :

$$\langle S_{x;z} (x;y) \rangle_{I} = \langle S_{x;z} (x; y) \rangle_{I}$$
  
 $\langle S_{y} (x;y) \rangle_{I} = \langle S_{y} (x; y) \rangle_{I}$ 

T >stands for the spin density induced where <by a longitudinal charge current I owing from lead 1 to lead 2. The rst two lines of Eq.(5) result from the symmetry operation i  $_{\rm y} P_{\rm x}$ , which has been known widely before<sup>8,28</sup>. The second two, however, are results from the symmetry operation  $i_x P_y$  and the Treversal operation together<sup>31</sup>. Firstly, due to the Treversal invariance, the equilibrium spin density vanishes when all chem ical potentials are equal in Eq.(4), i.e.,  $< S (x;y) >_{eq} = < S (x;y) >_{I} + < S (x;y) >_{I} = 0,$ where  $\langle S (x; y) \rangle_{I}$  denotes the spin density induced by a longitudinal charge current I from lead 2 to lead 1. Secondly, due to the geom etry sym m etry of the system under the manipulation i  $_{x}P_{v}$ , we have  $< S_{x}(x;y) > _{I} = <$  $S_x (x;y) > I$  and  $S_{y;z} (x;y) > I = S_{y;z} (x;y) > I$ . Combining these two results, we get the last two lines in Eq.(5).

In Fig.3 we plot the longitudinally averaged spin density inside the Rashba bar as a function of the transverse position y, where < S (y) > <sup>L</sup> denotes the longitudinal averaged value of < S (x; y) > along the x direction ( i.e., the direction of the charge current ow ). Due to the sym metry relations shown in Eq.(5), the non-vanishing components are < S<sub>y;z</sub> (y) > <sup>L</sup>. Moreover, under the spatial rejection manipulation y ! y, < S<sub>y</sub>(y) > <sup>L</sup> is even and < S<sub>z</sub>(y) > <sup>L</sup> is odd. The fact that the out-

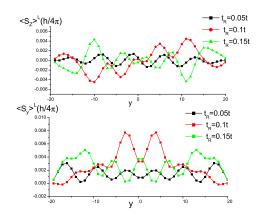


FIG.3: (Coloronline)Non-equilibrium spin density averaged in longitudinal direction in SO system , <  $\rm S_{y;z} > L$ , as a function of transverse position, y. The y and z components has di erent re ection symmetry with respect to x axis. The sign near the boundaries can be ipped by tuning Rashba coupling strength  $t_R$ .

ofplane component <  $S_z(y) > L$  has opposite signs near the two lateral edges is consistent with the phenom enology of SHE<sup>16,25</sup>. But for a two-term inal lattice structure with general lattice sizes, our results show that the spin density does not always develop peak structures near the

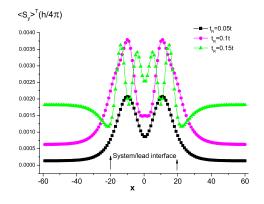


FIG.4: (Color online)The variation of spin density averaged in transverse direction of lead 2 versus R ashba coupling constant.

two boundaries but oscillate across the transverse direction. This is somehow di erent from the naive picture of spin accumulation near the boundaries due to a spin Hall current. The in-plane spin polarization is not related to the phenomenology of spin Hall e ect. It can be regarded as a general magnetoelectric e ect due to spin-orbit coupling<sup>32</sup>. It should be noted that, from the theoretical points of view, the relationship between spin current the induced spin polarization is actually a much subtle issue and is currently still under intensive debates. In this paper, how ever, we will free our discussions from such controversial issues.

It is evident from Fig. 3 that not only the magnitude, but also the sign of the spin accumulation near the two transverse boundaries can be changed by tuning the Rashba coupling strength. This is also reported in Ref<sup>28</sup> for a continuum two-term inalm odel. Since the Rashba coupling strength can be tuned experimentally through gate voltage, such a ipping behavior for spin accumulation m ight provide an interesting technological possibility for the electric control of the spin degree of freedom.

Now we present the most in portant theoretical prediction of this paper, i.e., the charge-current induced spin polarization e ect in the contacted leads. Due to the rst two lines in Eq.(5), after taking average in the transversal direction (which will be denoted by  $\langle S \rangle^T$  as a function of the longitudinal coordinate  $x_2$  ), only <  $S_v > T$ will remain nonzero. In Fig. 4 <  $S_y > T$  is plotted versus the longitudinal coordinate x of the whole system . The lattice size of the whole system is set to 120 40, while the central 40 lattice sites represents the Rashba SO bar (see Fig.1). A s indicated clearly in the gure, the border between the Rashba bar and the contacted leads are at 20. The Rashba SO coupling strength is chosen x = to be  $t_R = t = 0.05; 0.1; 0.15$ . As can be seen from Fig. 4,  $< S_v >^T$  changes with the coordinate x both inside the Rashba bar and in the leads, but in the leads it changes

with the coordinate x only in a much narrow region close to the border between the leads and the R ashba bar and will reach to a xed value further away from the border. This phenom enon is the lead spin polarization e ect in this paper. Theoretically, this phenom enon can be understood as following. For an incident wave (m; ) with a Ferm i energy  $E_f$  in lead 1, the potentiant wave function in lead 2 is:  $\lim_{n \to \infty} (x_2; y_2) = \lim_{n \to \infty} \lim_{n \to \infty} e^{ik_n x_2} n (y_2)$ , where  $2t\cos(k_n) + "_n = E_f$ . Then the spin density  $\leq S(x_2; y_2) > can be calculated as (dropping o a normalization factor),$ 

Thus, after taking average along the transversal direction, we have

. .

< 
$$S(x_2) > T = (1=N_2)^{X} < S(x_2;y_2) >$$
  
 $/ X_{m;} \frac{1}{v_{1m}} X_{n;;} [1m_{2n} e^{ik_n x_2}) ~; (1m_{2n} e^{ik_n x_2})](6)$ 

where we have used the orthogonality relation for the  $y_2 = n (y_2) = n n^0 \cdot E vidently,$ transverse m odes: ] in E  $\mathbf{\hat{q}}$ ). is independent of  $\mathbf{x}_2$  as long the sum m and [ as k<sub>n</sub> is real (i.e., for those longitudinal propagating modes). If  $k_n$  is in aginary, the corresponding mode will describe an exponentially localized state in lead 2 in the vicinity of the border between the lead and the Rashba bar. Such evanescent com ponents<sup>27</sup> can contribute to the local charge density and spin density only in the vicinity of the border. At some distance far away from the interface, the contribution of the evanescent modes to  $< S(x_2) > T$  will decay exponentially as  $x_2$  increase and hence  $\langle S(x_2) \rangle^T$  will be independent of  $x_2$ , as illustrated in Fig. 4. This result in plies that the spin polarization inside the Rashba bar can be inducted out by the driving charge current to the leads and m an ifest itself in an amplied way, i.e., the leads will become spin polarized and thus an electric-controllable spin state in the leads can be realized. Such a lead spin polarization e ect m ight be more easily detectable by magnetic or optical m ethods than the spin polarization inside the m esoscopic Rashba bar.

The results presented above is obtained in the absence of in purity scattering. To simulate spin-independent disorder scattering, we assume a uniform ly distributed random potential w 2 [ $W_D$ ;  $W_D$ ] in the Rashba barw ith a disorder strength  $W_D$ . The non-equilibrium spin density can be obtained by taking average for a number of random realizations of local potentials. We averaged 1000 random realizations in all calculations. In Fig. 5 we show how the curves of  $< S_y >^T$  versus x change with  $W_D$ . All curves are calculated with  $t_R = 0.1t$ . Noticeably, inside the Rashba bar the height of  $< S_y >^T$  decreases with increasing  $W_D$  but the lead spin polarization will rstly increase in the weak disorder regime ( $W_D < 0.5t$ ) and

FIG.5: (Color online)The variation of spin density averaged in transverse direction versus longitudinal coordinate at the presence of disorder scattering.

then decrease in the stronger disorder regime (note that our calculations are carried out under the condition of a xed longitudinal charge current density). Thus, there exists a certain regime in which disorder can enhance the saturation value of the spin polarization in the leads. The slight asymmetric form of W<sub>D</sub> = 2t line means that we need to take more random con gurations of local potential for large W<sub>D</sub> value, which is reasonable. Of course, there are some other factors such as spin-orbit coupling or in purity scattering in the leads that may reduce or suppress the lead spin polarization e ect. Further quantitative study is needed in order to clarify the role of these factors.

## IV. CONCLUSION

To conclude, in this paper we have presented a theoretical study on the non-equilibrium lead spin polarization e ect in a two-term inal m esoscopic R ashba bar under the condition of a xed longitudinal charge current density. We have predicted that a nite amount of non-equilibrium spin polarizations can be induced in the leads by the spin-orbit coupling inside the mesoscopic Rashba bar when the longitudinal charge current circulate through it. Such a lead spin polarization e ect can survive in the presence of weak disorder inside the Rashba bar and thus might be observable in real experiment. Such an e ect might provide a new kind of electric-controllable spin state which is technically attractive. But it should be stressed that, for real system s, due to the existence of disorder scattering or spin-orbit interactions or other spin decoherence e ects in the leads, the lead spin polarization e ect predicted in the present papermay be weakened. These factors need to be claried by m ore detailed theoretical investigations in the future.

## A cknow ledgm ents

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